

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

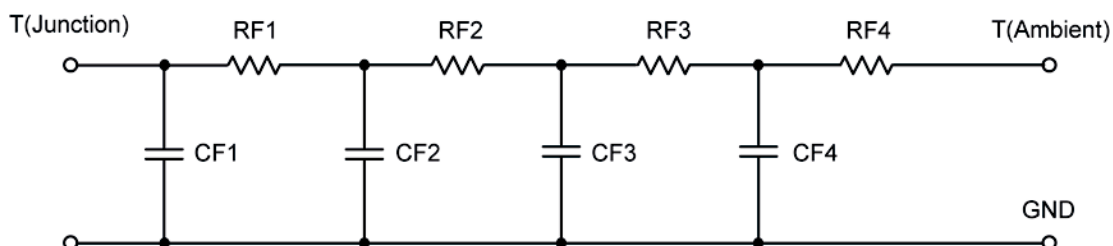
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	55.6413	N/A	28.3883
RT2	30.9887	N/A	4.9646
RT3	40.7212	N/A	32.4345
RT4	17.1737	N/A	19.0283
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.2066	N/A	3.2011 m
CT2	106.5145 m	N/A	187.9158 u
CT3	7.0362 m	N/A	8.6104 m
CT4	1.0161 m	N/A	1.1302 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ($^{\circ}\text{C}/\text{W}$)			
Junction to	Ambient	Case	Foot
RF1	23.3238	N/A	14.8964
RF2	39.9346	N/A	43.8024
RF3	31.3820	N/A	14.1733
RF4	50.2764	N/A	11.8627
Thermal Capacitance (Joules/ $^{\circ}\text{C}$)			
Junction to	Ambient	Case	Foot
CF1	914.3375 u	N/A	263.3136 u
CF2	6.4120 m	N/A	1.0199 m
CF3	99.8010 m	N/A	5.9506 m
CF4	1.2623	N/A	4.1288 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

